

To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

Send any inquiries to <http://www.renesas.com/inquiry>.

Notice

1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
2. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
7. Renesas Electronics products are classified according to the following three quality grades: “Standard”, “High Quality”, and “Specific”. The recommended applications for each Renesas Electronics product depends on the product’s quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as “Specific” without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as “Specific” or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is “Standard” unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - “Standard”: Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - “High Quality”: Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - “Specific”: Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics.
12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.

(Note 1) “Renesas Electronics” as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.

(Note 2) “Renesas Electronics product(s)” means any product developed or manufactured by or for Renesas Electronics.

R8C/25 Group

Six Step Trapezoidal Control of a BLDC Motor Using Back-EMF

Introduction

This document describes a method of commutating a 3-Phase Brushless DC (BLDC) motor using Back-EMF (BEMF) signals.

This document is intended to supplement the understanding of 6-step BLDC motor control using BEMF detection as one of many possible methods of commutation. The BEMF-detection method, as well as the Hall device method, are implemented on the Renesas YMCRPR8C25 Motor Control Evaluation kit, which provides an excellent platform for developing the algorithm for individual applications.

The reader should already have some understanding of six-step commutation methods, such as Hall commutation, to provide background to the techniques described here. The reader is encouraged to first read the 6-Step Motor Drive with HALL sensor Application Note referred to in the Reference section at the end of this document.

Target Devices

R8C/24 and R8C/25

Contents

1. Motor Back-EMF Signal Characteristics	2
2. Detecting Back-EMF Signals for Commutation.....	3
3. Driving BLDC Motor for Back-EMF Commutation.....	5
4. Open-Loop Alignment and Rotation Starting	6
5. How to deal with Inductive Effects	7
6. Summary	8
7. Reference.....	9

1. Motor Back-EMF Signal Characteristics

A 3-phase Permanent Magnet Brushless DC (PM-BLDC) motor generates 3-phase AC voltages (shown in Figure 1) called a Back Electro-Motive Force (also Back-EMF or BEMF) as it rotates. The amplitude and frequency of the generated voltage are proportional to the rotational speed. If the motor has a single pole pair on the rotor (one North and one South pole) then the Frequency of the BEMF voltage will be the same as the rotational speed of the rotor. If, however, it has multiple magnetic poles (as motors often do), then the frequency will be higher, in proportion to the number of pole pairs on the rotor. The voltage generated will be determined by the number of turns in the windings and the strength of the rotor magnet. There will be a relationship then that can be established with the motor where it will generate a particular AC voltage when it is spinning at a particular speed. This value can be expressed as a constant K_e , it equals the volts generated at some RPM, usually 1000 RPM. Motor manufacturers usually provide the value of this constant.

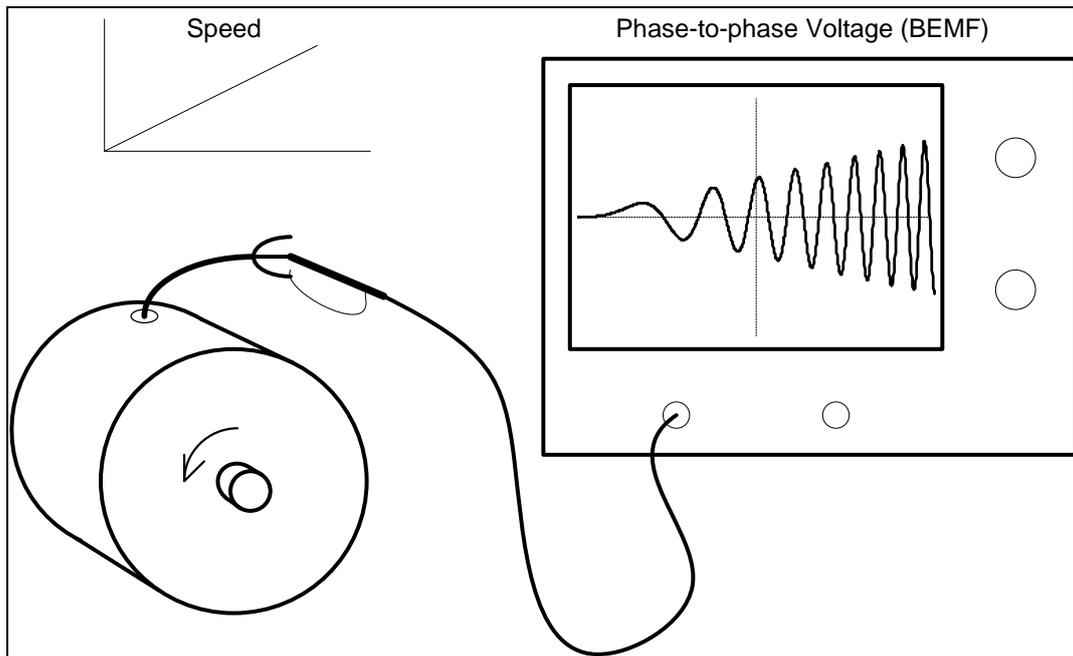


Figure 1 Voltage and frequency measured externally at rotating BLDC motor

In most BLDC motors, we normally only have access to the three windings, not to the center tap (neutral), so the voltages have to be seen between two phases where it is the difference of the voltages between those windings. If one voltage is near maximum, and the other is near minimum, then the voltage seen between them will be larger than if the two phases were both positive or were both negative, relative to the neutral. For the purpose of commutation with the BEMF signals, we want to know when a phase voltage crosses zero with respect to the neutral. As it happens, when one phase is crossing neutral, the other two phases are at equal and opposite voltages, so we can detect a zero crossing of one phase when its measured voltage is exactly between the other two. For purposes of this document, we will assume that BLDC motors are always constructed symmetrically, with similar BEMF, resistance and inductance in all three phases.

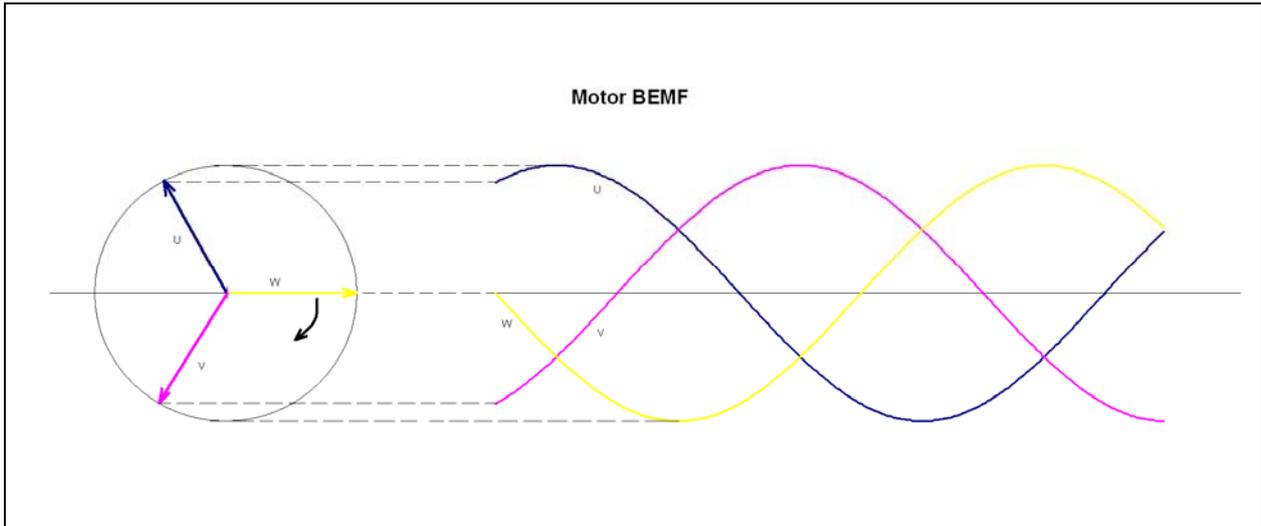


Figure 2 Rotating vector representation of motor phases

2. Detecting Back-EMF Signals for Commutation

The voltage present on the motor phases is a combination of those generated internally and of those being driven externally by our transistors with PWM voltages. So, detecting BEMF on an undriven motor is easy, but not so when we are also trying to force current into the windings to generate torque and cause it to spin. The internal voltages are due to the BEMF and to affects from the resistance and inductance of the motor which are functions of the current flowing in the windings. The PWM voltages that we use to drive the motor windings externally will likely be much higher than the BEMF voltages we are trying to detect. Despite this, we need some way of seeing the BEMF voltage near the time when the phase crosses zero, so we can decide when to commutate. In order to get a clean representation of the BEMF voltage, it is necessary to filter the high frequency PWM signals from the motor phase voltage, leaving only the lower frequency BEMF signal. After that, we can also deal with the voltages due to the resistive and inductive effects.

For example, if we use a common PWM carrier frequency of 12 kHz, the BEMF frequency will likely be much lower, around a few hundred Hz. The exact value of the BEMF frequency can be found as $BEMF_Hz = RPM \times (1 \text{ min}/60 \text{ sec}) \times \text{Number_of_Pole_Pairs}$. So, for a motor with 5 pole pairs, running at 3000 RPM, the BEMF frequency is 250 Hz. The difference between 12 kHz and 250 Hz allows us some room to create a low-pass filter that will pass the BEMF component, while attenuating the PWM component.

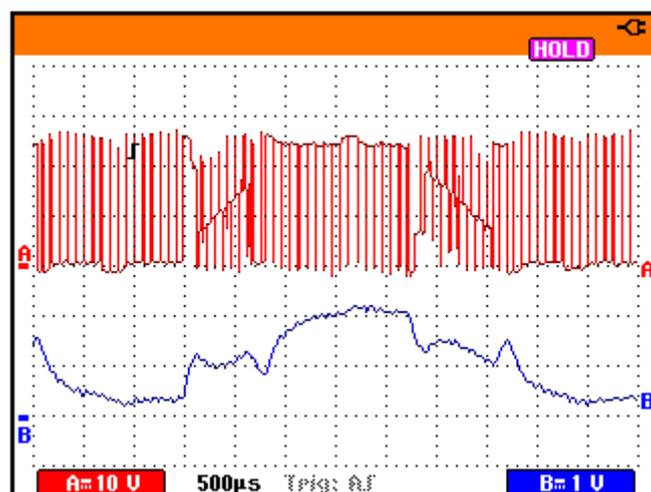


Figure 3 Raw and filtered motor voltage

Assuming the bus voltage is higher than the logic-level voltages, then the motor voltage should be also divided down to scale it to those that can be observed by the comparator logic. The circuits used to scale down and filter the motor phases voltages are shown below in Figure 4. The U, V and W are the motor lines, with PWM and BEMF components

up to 50V (divided by a factor of 10) and the V_U, V_V and V_W lines are the scaled and filtered BEMF signals which are fed into comparators.

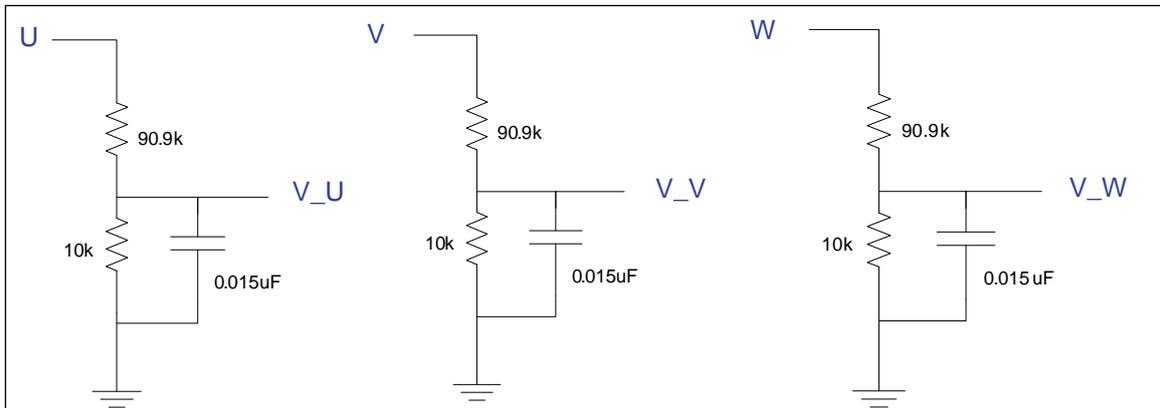


Figure 4 Filtering and Scaling of phase voltages to match the logic levels

Once we have the BEMF voltages filtered and scaled, we compare it with a reference point, derived from the bus voltage. We do this because the motor phases are modulated from the bus, and if the bus voltage varies by any amount, the reference and phase voltage will remain proportional. One difference from the motor filter and divider is that the bus reference is scaled at half the value. In this way, the bus reference will always be at a point where we can detect when the phase voltage is above or below the 50% value, which we will see, is a convenient way for detecting the zero crossing in the BEMF voltages.

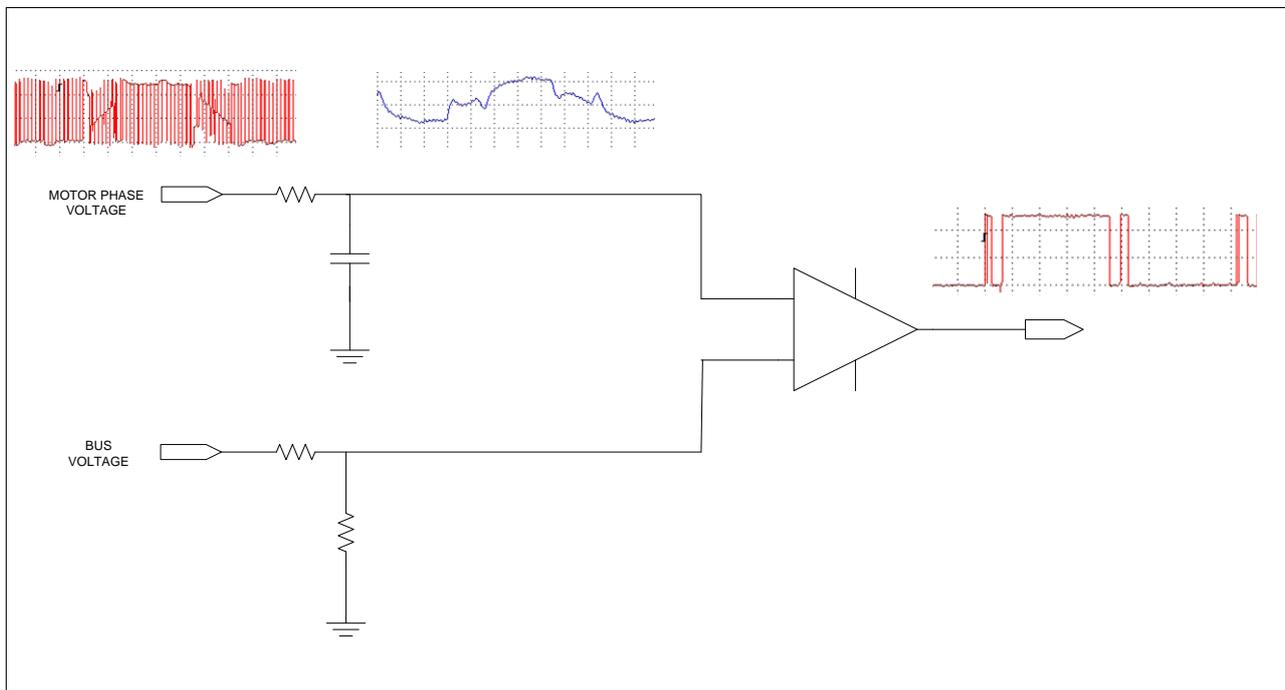


Figure 5 Simplified BEMF comparator signals

The next step is to modulate the motor in such a way as to keep the motor neutral very close to half the bus voltage so that when a phase does a zero crossing, it can be detected by the comparator at the half-bus reference point.

3. Driving BLDC Motor for Back-EMF Commutation

For complementary PWM, each comparator register in the PWM timer produces two PWM outputs, not just one. The two complementary signals are used in one phase of the three phase PWM, so there are a total of three comparator registers and six PWM outputs or three pairs. One of each pair is designated as the upper transistor driver, and the other is the lower. We use the convention that as the PWM compare value increases, the upper transistor duty for that phase becomes larger, and the lower duty becomes smaller. The two signals are complementary in that they are the logical inversion, or complement, of the other, so that the two signals are not active at the same time. In reality, the TimerRD also allows “deadtime” settings, which introduces a period of time when both pulses are inactive, to allow for switching time in the transistors. See the R8C/25 hardware manual for more detail on TimerRD used in Complementary PWM mode.

As mentioned above, we need to apply voltages which are centered about the middle of the bus in order to allow zero-crossings to be detected at the half-bus reference. We can do this type of voltage driving to the motor phases using voltages symmetric about the half-bus level. We use complementary PWM and a reference level of 50% PWM duty for both the higher and lower side voltages on two of the phases.

We set up the PWM output near a value of 50% for both driven phases, but increase one phase duty by some amount and lower the other phase the same amount. For example, if we drive phase U to 60% duty, then we can drive phase V at 40% duty, the difference is 20%, as will be seen by the motor phases, and the middle of the two will still be 50%, where we are detecting the zero-crossing on phase W. A look at the voltage present at phase W will still have the PWM components of the other two phases, but once filtered, the PWM components of phases U and V will be removed, leaving the correct representation of the phase W voltage. When the phase W signal crosses the middle of the bus, it is also the same angle where phase U and V are equal and opposite and also balanced around the middle of the bus, so our assumption of symmetry allows us to detect that phase W has crossed zero without measuring the neutral point directly. Voltage drops caused by the resistance in the other phases are cancelled, since the current through the other phases must also be equal.

In the software, this method of symmetrical modulation is easy to implement. For any given duty desired, we normalize it to the range of 50% duty, then add or subtract that value from a set value of 50% for two of the phases. So, if we have 1024 counts of PWM total (meaning that a value of 1024 will give us 100% duty PWM on the upper channel and 0% on the lower), then 50% (for both upper and lower, in complement) will be a timer compare value 512. For a motor needing apparent 50% duty, we actually add 25% to 50% for one phase and subtract 25% from 50% for the other, creating a total of 50%, but each only 25% offset from the 50% reference. We can now guarantee that the motor neutral will be very near the center of the bus when the undriven phase crosses zero on its BEMF output.

Of course, only two of the phases are being driven at one time, the floating phase is the one being observed for BEMF crossing. Once a decision is made to commutate and switch the transistors, the floating phase should be the one next approaching the zero crossing. We use the data from the present commutation state (or Step), along with the zero crossing detection to continue moving the motor to the next Step, and so on.

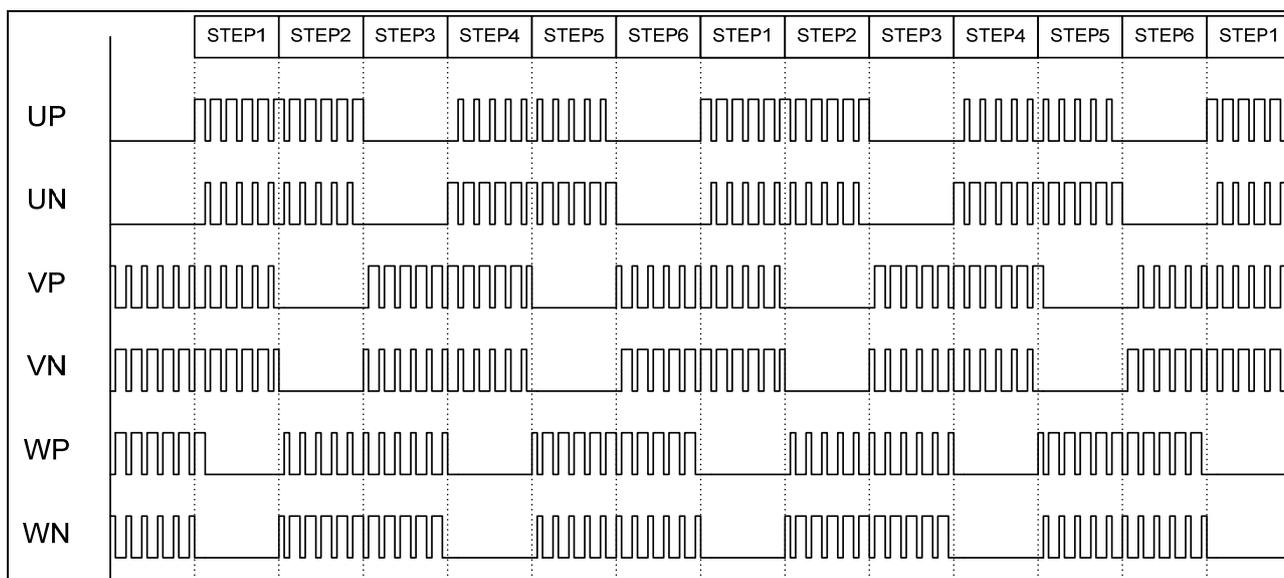


Figure 6 Simulated PWM signals

Since the BEMF detection is done by observing the phase voltage, which is a function of speed and of the driving voltage of our PWM, it is necessary to get the motor running at some speed before the BEMF voltage is large enough to be detected. So, for starting the motor from full stop, where no BEMF voltage exists, we have to force the motor to spin first before we can use BEMF detection to continue the commutation. For that, we use open-loop alignment and start-up techniques.

4. Open-Loop Alignment and Rotation Starting

The method of commutating by detecting BEMF voltages requires that the motor is already spinning and generating a reasonable amplitude BEMF signal before commutation can be done.

To make that happen, we first force the rotor into a known position in an alignment process. This can be done by setting the voltage on Phase U higher than V and W. That is done by setting PWM counts for U higher and the counts in V and W smaller. Though alignment can be done with only two phases, by applying the same voltage to two of the phases produces a natural damping effect to help the motor settle more quickly into the alignment position.

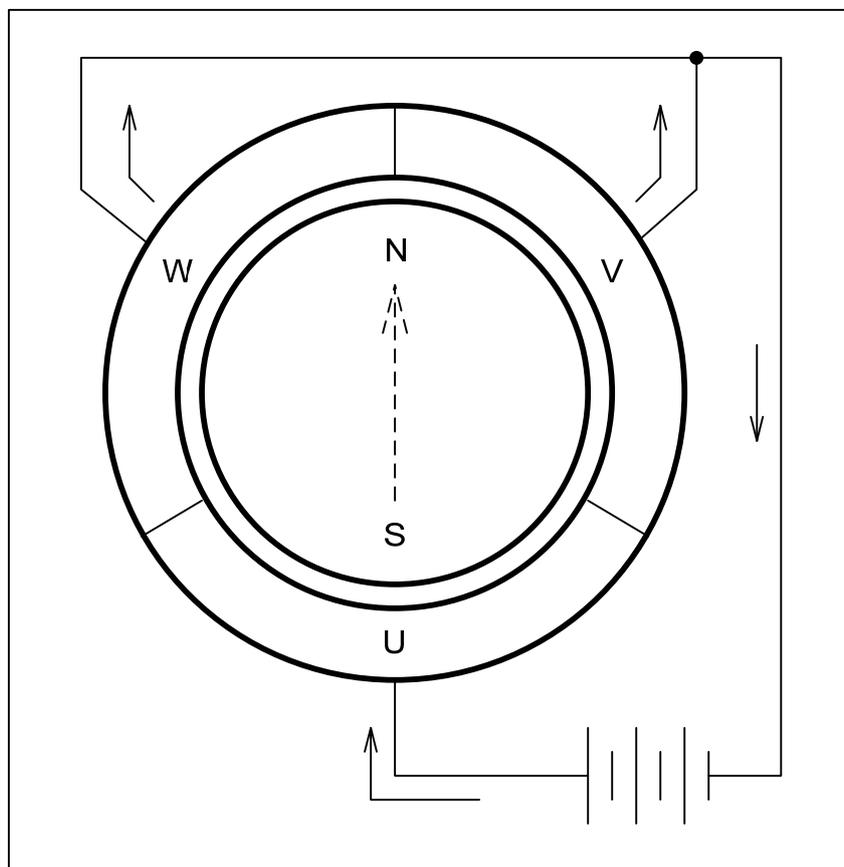


Figure 7 Concept of alignment current

We slowly increase this voltage (that is, the PWM duty), to not impart an impulse to the motor, which may cause it to oscillate. We do this process for up to several seconds, to allow the rotor to align with the currents, and to allow any spontaneous rotational oscillation to dampen out. Small motors with low inertia may align in less than a second, while large inertia loads require more time.

Once we are sure the motor is in a known alignment state, we begin sending a slowly accelerating stepped current into the motor phases to get the motor to spin in the desired direction. We commutate as in Figure 6 above, increasing and cycling through the Step count as we go. The initial duty cycle is selected to overcome the frictional forces and inertia of the motor. We increase the voltage sent to the phases as well as increase the step rate to force the motor to turn and accelerate, overcoming the motor friction, inertia and the increasing back-EMF. Because there is no commutation feedback during this stage to keep the currents aligned with the rotor, the open-loop currents must be larger than normal to maintain the torque. It is important, therefore, to set the alignment voltage and time, as well as the ramp rate and voltage to match the motor and load to ensure a reliable start.

The software should increase the open-loop commutation switch rate until such time that the BEMF is large enough to generate reliable signals into the comparators. That rotational speed can be found by examining the BEMF signals during hall commutation (if available) or empirically by selecting arbitrary speeds and checking results. Once the motor has accelerated in the open-loop to our switch point, it is just a matter of changing over to the BEMF modulation method, where the comparator output state determines the motor phase drive. Once BEMF commutation kicks in, the motor current can be reduced since the voltage fed will now align with the motor BEMF signal, increasing the torque. It is now possible to increase the ramp of applied voltage and accelerate the motor at a higher rate to the speed desired. Figure 8 shows a waveform of this as the motor begins with alignment current, accelerates with open-loop current, then when switched to BEMF commutation, the current required goes down significantly.

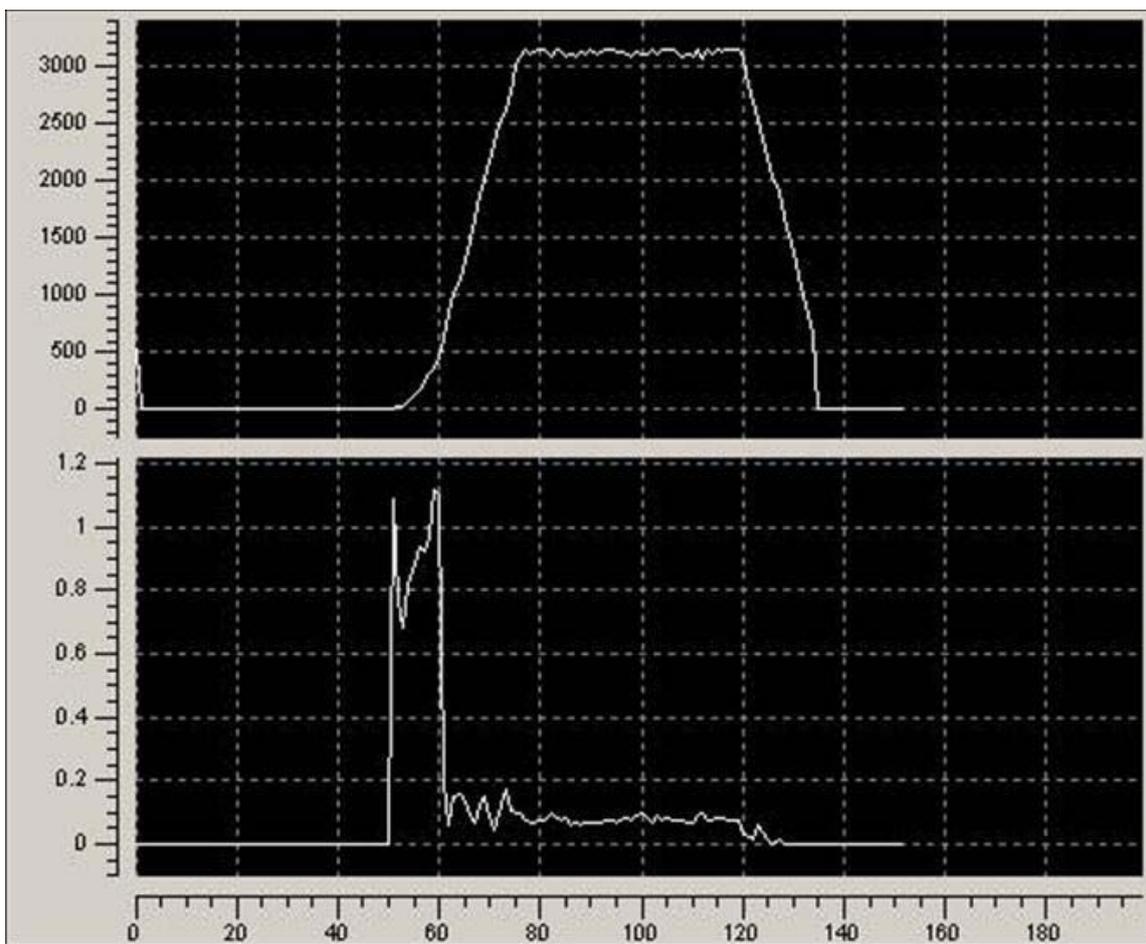


Figure 8 Speed and current waveforms

5. How to deal with Inductive Effects

Commutating a BLDC motor (where the windings always have some inductance) means that there will be inductive effects from changes in current on the voltage waveforms. The nature of inductance is to resist changes in current, and larger changes in current require large voltage to be applied. Likewise, when current is forced to change during the switching action of the transistors, large voltages can occur spontaneously in the windings, often called “inductive kick”. When a phase is switched to float, the remaining current will decay, during which time the inductive kick will force the voltage of a floating phase to discharge to one of the power rails (through diodes parallel with the transistors). The length of time that this current discharge happens is proportional to the amount of current to be dissipated, and inversely to the difference in voltage between the phase BEMF and the power rail.

Under low current conditions, the voltage pulse generated by the inductive kick is short in duration. Under larger current, as when the motor load is larger, the time for the voltage to decay is longer. It is important to note that this time must not be so long as to prevent the detection of the normal zero-crossing of the undriven phase, or BEMF commutation is not possible. Assuming the current discharge time is short enough, then a masking interval can be used to ignore the pulse at the output of the comparator. Selecting the right masking time is critical since if masking time is

too short, invalid commutation signals will cause currents to be switched to the wrong phase and decrease motor efficiency. If the masking time is too long, the commutation rate is limited therefore the motor speed will be limited. We use a timer in the software to mask the voltage pulses. This count is defined in software as a count on the PWM timer and can be changed for different motors and load conditions. Once the masking time interval has passed, we begin looking at the comparator output for a change which would indicate a valid change in step. Once that is detected, we begin the timer again to mask the next voltage pulse for the same period of time.

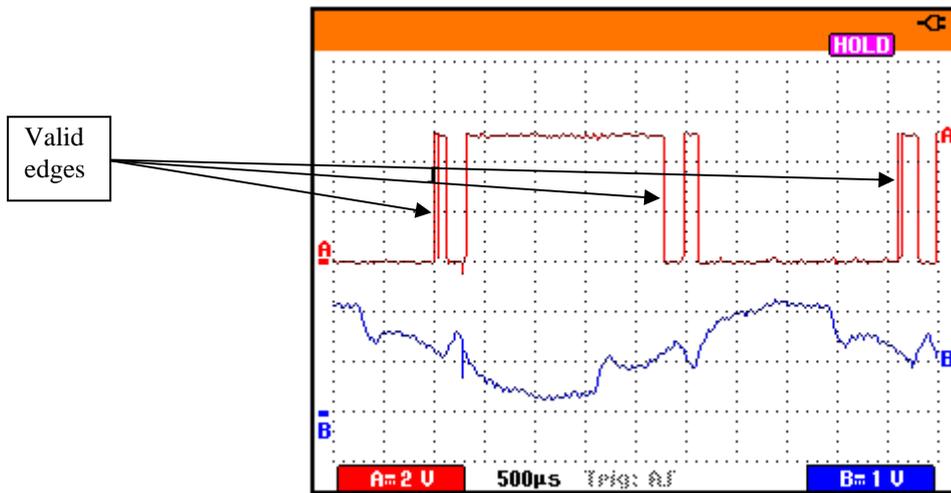


Figure 9 Filtered Back EMF and comparator output

Figure 9 shows a graph showing the comparator output, including the voltage pulse to be masked. The blue trace (bottom) is the filtered BEMF, and the red trace (top) is the comparator output with extra edges. The first edge is the valid one, the next two or three quickly following are the invalid edges, caused by the inductive pulse.

If we imagine the same comparator signals, but without the extra edges caused by the inductance, then what we find is that the three comparator signals are nearly identical to what we would expect from Hall device signals. So, we can use the comparator signals in much the same way we would with Hall signals, and use their state to determine the commutation state. This is exactly what we do in the sample motor code supplied with the YMCRPR8C25 kit. The BEMF code uses the three comparator edges, filters out the unwanted edges, and uses their state in a lookup table to decide which transistors are switched to high, low, or float.

6. Summary

In this application note we described a method of commutating a 3-Phase Brushless DC (BLDC) motor using Back-EMF (BEMF) signals. The Renesas YMCRPR8C25 Motor Control kit is an excellent vehicle for evaluating BEMF control using the R8C/Tiny Microcontroller devices. Offering a rich set of Motor Control peripherals, the R8C25 series is specifically suited for 3-phase motor control, including the BEMF method described here, as well as Hall-based commutation and AC Induction motor control.

7. Reference

YMCRPR8C25 Kit

User Manual

Application Notes

REU05B0074-0100/Rev.1.00 Six-Step Trapezoidal Control of a BLDC Motor Using Hall Sensors
REJ05B0845-0100/Rev.1.00 Timer RD in Complementary PWM Mode
REJ05B0486-0100Z/Rev.1.00 Solutions for Three-Phase Motor Control Programming

Hardware Manual

R8C/24 Group, R8C/25 Group Hardware Manual Rev. 1.0
YMCRPR8C25 Motor Control Demo Kit
(Use the latest version on the home page: <http://www.renesas.com>)

Website and Support

Renesas Technology Website
<http://www.renesas.com/>

Technical Contact Details:

Global: csc@renesas.com

Inquiries

<http://www.renesas.com/inquiry>

Revision Record

Rev.	Date	Description	
		Page	Summary
1.00	Feb.05.08	—	First edition issued
1.01	Feb.02.09	10	Disclaimer changed

Notes regarding these materials

1. This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of Renesas or any third party with respect to the information in this document.
2. Renesas shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.
3. You should not use the products or the technology described in this document for the purpose of military applications such as the development of weapons of mass destruction or for the purpose of any other military use. When exporting the products or technology described herein, you should follow the applicable export control laws and regulations, and procedures required by such laws and regulations.
4. All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas products listed in this document, please confirm the latest product information with a Renesas sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas such as that disclosed through our website. (<http://www.renesas.com>)
5. Renesas has used reasonable care in compiling the information included in this document, but Renesas assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document.
6. When using or otherwise relying on the information in this document, you should evaluate the information in light of the total system before deciding about the applicability of such information to the intended application. Renesas makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or Renesas products.
7. With the exception of products specified by Renesas as suitable for automobile applications, Renesas products are not designed, manufactured or tested for applications or otherwise in systems the failure or malfunction of which may cause a direct threat to human life or create a risk of human injury or which require especially high quality and reliability such as safety systems, or equipment or systems for transportation and traffic, healthcare, combustion control, aerospace and aeronautics, nuclear power, or undersea communication transmission. If you are considering the use of our products for such purposes, please contact a Renesas sales office beforehand. Renesas shall have no liability for damages arising out of the uses set forth above.
8. Notwithstanding the preceding paragraph, you should not use Renesas products for the purposes listed below:
 - (1) artificial life support devices or systems
 - (2) surgical implantations
 - (3) healthcare intervention (e.g., excision, administration of medication, etc.)
 - (4) any other purposes that pose a direct threat to human life

Renesas shall have no liability for damages arising out of the uses set forth in the above and purchasers who elect to use Renesas products in any of the foregoing applications shall indemnify and hold harmless Renesas Technology Corp., its affiliated companies and their officers, directors, and employees against any and all damages arising out of such applications.
9. You should use the products described herein within the range specified by Renesas, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas shall have no liability for malfunctions or damages arising out of the use of Renesas products beyond such specified ranges.
10. Although Renesas endeavors to improve the quality and reliability of its products, IC products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Please be sure to implement safety measures to guard against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other applicable measures. Among others, since the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
11. In case Renesas products listed in this document are detached from the products to which the Renesas products are attached or affixed, the risk of accident such as swallowing by infants and small children is very high. You should implement safety measures so that Renesas products may not be easily detached from your products. Renesas shall have no liability for damages arising out of such detachment.
12. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written approval from Renesas.
13. Please contact a Renesas sales office if you have any questions regarding the information contained in this document, Renesas semiconductor products, or if you have any other inquiries.

© 2008. Renesas Technology Corp., All rights reserved.